

# CNZ2153

## Reflective Photosensor

### ■ Overview

CNZ2153 is a photosensor detecting the change of reflective light in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a Si phototransistor is used as the light detecting element. The two elements are located parallel in the same direction and objects are detected when passing in front of the device.

### ■ Features

- Fast response
- Small size and light weight

### ■ Applications

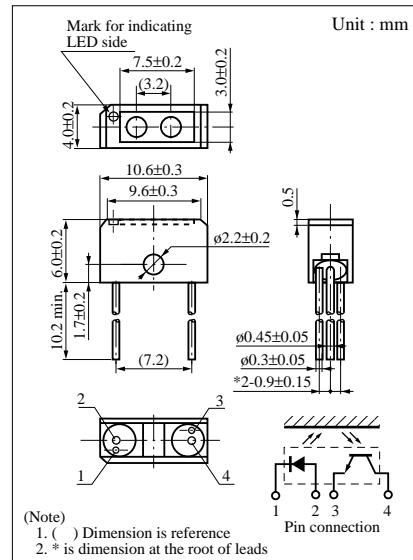
- Detection of paper, film and cloth
- Optical mark reading
- Detection of position and edge
- Detection of coin and bill
- Start, end mark detection of magnetic tape

### ■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter		Symbol	Ratings	Unit
Input (Light emitting diode)	Reverse voltage (DC)	$V_R$	3	V
	Forward current (DC)	$I_F$	50	mA
	Power dissipation	$P_D$ <sup>*1</sup>	75	mW
Output (Photo transistor)	Collector to emitter voltage	$V_{CEO}$	30	V
	Emitter to collector voltage	$V_{ECO}$	5	V
	Collector current	$I_C$	20	mA
Temperature	Collector power dissipation	$P_C$ <sup>*2</sup>	50	mW
	Operating ambient temperature	$T_{opr}$	-25 to +85	°C
	Storage temperature	$T_{stg}$	-30 to +100	°C

<sup>\*1</sup> Input power derating ratio is 1.0 mW/°C at  $T_a \geq 25^\circ\text{C}$ .

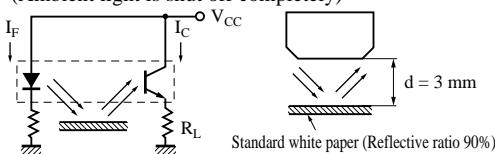
<sup>\*2</sup> Output power derating ratio is 0.67 mW/°C at  $T_a \geq 25^\circ\text{C}$ .



### ■ Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Parameter		Symbol	Conditions	min	typ	max	Unit	
Input characteristics	Forward voltage (DC)	$V_F$	$I_F = 50\text{mA}$			1.2	1.5	V
	Reverse current (DC)	$I_R$	$V_R = 3\text{V}$			10		μA
	Capacitance between terminals	$C_t$	$V_R = 0\text{V}$ , $f = 1\text{MHz}$		50			pF
Output characteristics	Collector cutoff current	$I_{CEO}$	$V_{CE} = 10\text{V}$			0.2		μA
	Collector current	$I_C$ <sup>*1</sup>	$V_{CC} = 5\text{V}$ , $I_F = 20\text{mA}$ , $R_L = 100\Omega$	100				μA
	Response time	$t_r$ <sup>*2</sup> , $t_f$ <sup>*3</sup>	$V_{CC} = 10\text{V}$ , $I_C = 0.1\text{mA}$ , $R_L = 100\Omega$		6			μs
Transfer characteristics	Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_F = 50\text{mA}$ , $I_C = 0.1\text{mA}$			0.5		V

<sup>\*1</sup> Transfer characteristics measurement circuit  
(Ambient light is shut off completely)



<sup>\*2</sup> Time required for the collector current to increase from 10% to 90% of its final value.

<sup>\*3</sup> Time required for the collector current to decrease from 90% to 10% of its initial value.

